Product data sheet

1. General description

PNP low V_{CEsat} transistor in a SOT223 plastic package.

NPN complement: PBSS4540Z

2. Features and benefits

- · Low collector-emitter saturation voltage
- High current capability
- Improved device reliability due to reduced heat generation.

3. Applications

- Supply line switching circuits
- Battery management applications
- DC/DC converter applications
- · Strobe flash units
- Heavy duty battery powered equipment (motor and lamp drivers)
- · MOSFET driver applications.

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|---|---|-----|-----|-----|------|
| V _{CEO} | collector-emitter voltage | open base | - | - | -40 | V |
| I _C | collector current | | - | - | -5 | Α |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | - | - | -10 | Α |
| R _{CEsat} | collector-emitter saturation resistance | I_C = -2 A; I_B = -200 mA; pulsed; $t_p \le$ 300 µs; $\delta \le$ 0.02; T_{amb} = 25 °C | - | 55 | 80 | mΩ |

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|----------------------------|----------------|
| 1 | В | base | 4 | С |
| 2 | С | collector | | |
| 3 | Е | emitter | | B— |
| 4 | С | collector | ☐1 ☐2 ☐3 SC 72 (SOT222) | E sym132 |
| | | | SC-73 (SOT223) | , |



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6. Ordering information

Table 3. Ordering information

| Type number | Package | ckage | | | |
|-------------|---------|---|---------|--|--|
| | Name | Description | Version | | |
| PBSS5540Z | | plastic, surface-mounted package with increased heatsink; 4 leads; 2.3 mm pitch; 6.5 mm x 3.5 mm x 1.65 mm body | SOT223 | | |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PBSS5540Z | PB5540 |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|---------------------------|-------------------------------------|-----|-----|------|------|
| V _{CBO} | collector-base voltage | open emitter | | - | -40 | V |
| V _{CEO} | collector-emitter voltage | open base | | - | -40 | V |
| V_{EBO} | emitter-base voltage | open collector | | - | -6 | V |
| I _C | collector current | | | - | -5 | Α |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | | - | -10 | Α |
| I _{BM} | peak base current | | | - | -2 | Α |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 1.35 | W |
| | | | [2] | - | 2 | W |
| T _j | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -65 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

9. Thermal characteristics

Table 6. Thermal characteristics

| | Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|--|---------------------------------------|-------------------------|-------------|-----|-----|-----|-----|------|
| | · · · · · · · · · · · · · · · · · · · | thermal resistance from | in free air | [1] | - | - | 92 | K/W |
| | junction to ambient | | [2] | - | - | 62 | K/W | |

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

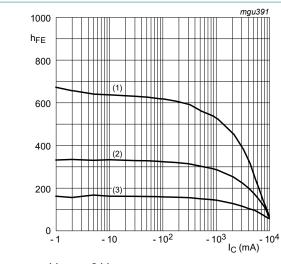
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10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|---|---|-----|------|-------|------|
| V _{(BR)CBO} | collector-base breakdown voltage | I _C = -100 μA; I _E = 0 A | -40 | - | - | V |
| V _{(BR)CEO} | collector-emitter breakdown voltage | I_C = -10 mA; I_B = 0 A; T_{amb} = 25 °C | -40 | - | - | V |
| V _{(BR)EBO} | emitter-base breakdown voltage (collector open) | $I_E = -100 \mu A; I_B = 0 mA; T_{amb} = 25 °C$ | -6 | - | - | V |
| I _{CBO} | collector-base cut-off | V _{CB} = -30 V; I _E = 0 A; T _{amb} = 25 °C | - | - | -100 | nA |
| | current | V _{CB} = -30 V; I _E = 0 A; T _j = 150 °C | - | - | -50 | μΑ |
| I _{EBO} | emitter-base cut-off current | V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C | - | - | -100 | nA |
| h _{FE} | DC current gain | V _{CE} = -2 V; I _C = -500 mA; T _{amb} = 25 °C | 250 | 350 | - | |
| | | V_{CE} = -2 V; I_{C} = -1 A; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C | 200 | 300 | - | |
| | | V_{CE} = -2 V; I_{C} = -2 A; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C | 150 | 250 | - | |
| | | V_{CE} = -2 V; I_{C} = -5 A; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C | 50 | 150 | - | |
| V _{CEsat} | collector-emitter | I _C = -500 mA; I _B = -5 mA; T _{amb} = 25 °C | - | -80 | -120 | mV |
| | saturation voltage | I _C = -1 A; I _B = -10 mA; T _{amb} = 25 °C | - | -120 | -170 | mV |
| | | I _C = -2 A; I _B = -200 mA; T _{amb} = 25 °C | - | -110 | -160 | mV |
| | | I _C = -5 A; I _B = -500 mA; T _{amb} = 25 °C | - | -250 | -375 | mV |
| R _{CEsat} | collector-emitter saturation resistance | I_C = -2 A; I_B = -200 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C | - | 55 | 80 | mΩ |
| V _{BEsat} | base-emitter saturation voltage | I _C = -5 A; I _B = -500 mA; T _{amb} = 25 °C | - | - | -1.3 | V |
| V_{BEon} | base-emitter turn-on voltage | V _{CE} = -2 V; I _C = -2 A; T _{amb} = 25 °C | - | -0.8 | -1.25 | V |
| f _T | transition frequency | V_{CE} = -10 V; I_{C} = -100 mA; f = 100 MHz; T_{amb} = 25 °C | 60 | 120 | - | MHz |
| C _c | collector capacitance | V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C | - | 90 | 105 | pF |

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V_{CE} = -2 V (1) T_{amb} = 150 °C (2) T_{amb} = 25 °C (3) T_{amb} = -55 °C

Fig. 1. DC current gain as a function of collector current; typical values

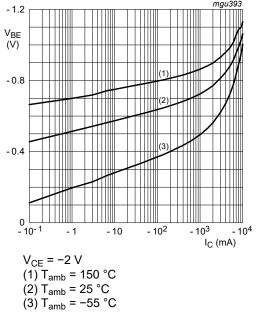
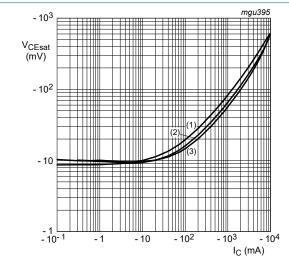


Fig. 2. Base-emitter voltage as a function of collector current; typical values



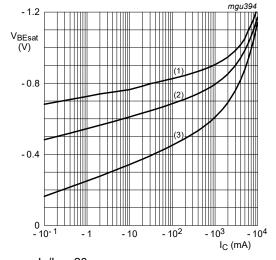
 $I_{\rm C}/I_{\rm B}=20$

(1) T_{amb} = 150 °C

(2) T_{amb} = 25 °C

(3) $T_{amb} = -55 \, ^{\circ}C$

Fig. 3. Collector-emitter saturation voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 20$

(1) T_{amb} = 150 °C

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = -55 \, ^{\circ}C$

Fig. 4. Base-emitter saturation voltage as a function of collector current; typical values

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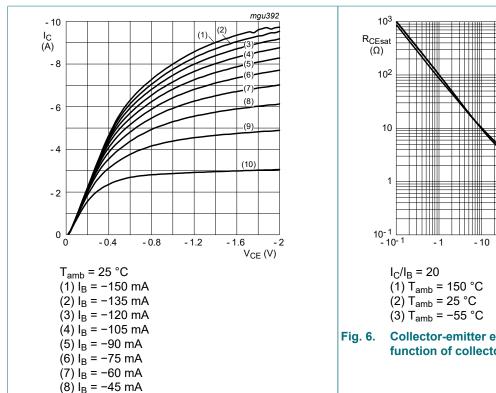


Fig. 6. Collector-emitter equivalent on-resistance as a function of collector current; typical values

- 10²

- 10³

I_C (mA)

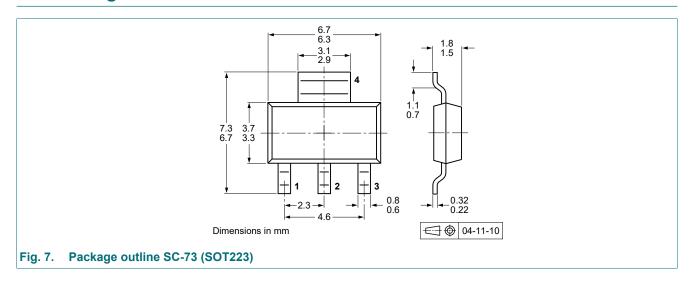
11. Package outline

Fig. 5.

(9) $I_B = -30 \text{ mA}$ (10) $I_B = -15 \text{ mA}$

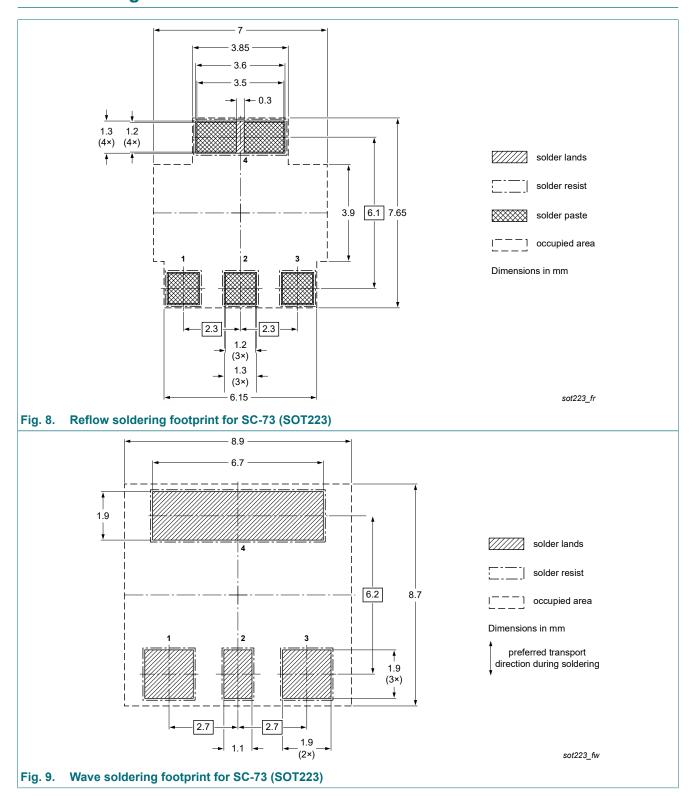
Collector current as a function of collector-

emitter voltage; typical values



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12. Soldering



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13. Revision history

Table 8. Revision history

| Table 6. Revision history | | | | | | | | |
|---------------------------|--------------|---|---------------|---------------|--|--|--|--|
| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes | | | | |
| PBSS5540Z v.4 | 20230401 | Product data sheet | - | PBSS5540Z v.3 | | | | |
| Modifications: | | Product changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s). | | | | | | |
| PBSS5540Z v.3 | 20190920 | Product data sheet | - | PBSS5540Z v.2 | | | | |
| PBSS5540Z v.2 | 20010921 | Product data sheet | - | PBSS5540Z v.1 | | | | |
| PBSS5540Z v.1 | 20010126 | Product data sheet | - | - | | | | |

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14. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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